

### FEATURES

- Turn On Current ( $I_{FT}$ ), 5.0 mA Typical
- Gate Trigger Current ( $I_{GT}$ ), 20  $\mu$ A
- Surge Anode Current, 1.0 Amp
- Blocking Voltage, 400 V
- Gate Trigger Voltage ( $V_{GT}$ ), 0.6 Volt
- Isolation Voltage, 5300  $V_{RMS}$
- Solid State Reliability
- Standard DIP Package
- Underwriters Lab File #E52744

### DESCRIPTION

The IL400 is an optically coupled SCR with a Gallium Arsenide infrared emitter and a silicon photo SCR sensor. Switching can be achieved while maintaining a high degree of isolation between triggering and load circuits. The IL400 can be used in SCR triac and solid state relay applications where high blocking voltages and low input current sensitivity are required.

### Maximum Ratings

#### Emitter

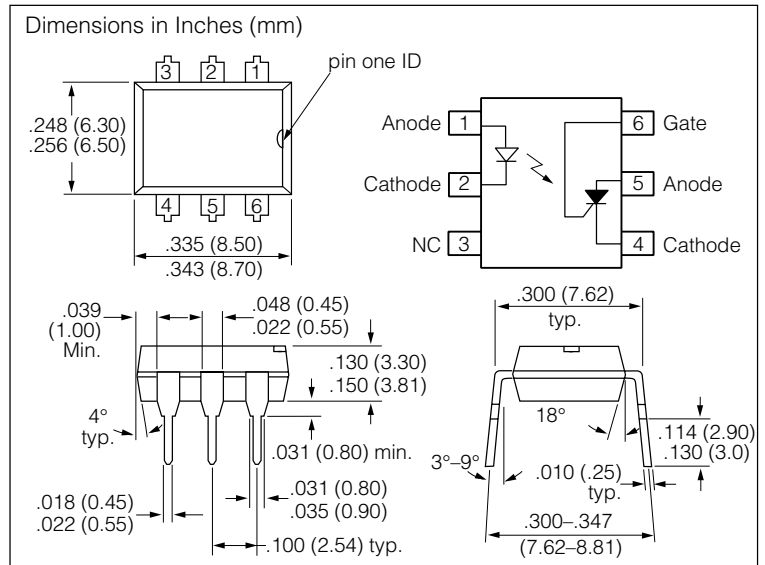
Peak Reverse Voltage ..... 6.0 V  
 Peak Forward Current  
 (100  $\mu$ s, 1% Duty Cycle) ..... 1.0 A  
 Continuous Forward Current ..... 60 mA  
 Power Dissipation at 25°C ..... 100 mW  
 Derate Linearly from 25°C ..... 1.3 mW/°C

#### Detector

Reverse Gate Voltage ..... 6.0 V  
 Anode Voltage (DC or AC Peak) ..... 400 V  
 Anode Current ..... 100 mA  
 Surge Anode Current (10 ms duration) ..... 1.0 A  
 Surge Gate Current (5.0 ms duration) ..... 200 mA  
 Power Dissipation, 25°C ambient ..... 200 mW  
 Derate Linearly from 25°C ..... 2.11 mW/°C

#### Package

Isolation Voltage ..... 5300  $V_{RMS}$   
 Isolation Resistance  
 $V_{IO}=500$  V,  $T_A=25^\circ$ C ..... min.  $10^{12}$   $\Omega$   
 $V_{IO}=500$  V,  $T_A=100^\circ$ C ..... min.  $10^{11}$   $\Omega$   
 Total Package Dissipation ..... 250 mW  
 Derate Linearly from 25°C ..... 2.63 mW/°C  
 Operating Temperature ..... -55°C to +100°C  
 Storage Temperature ..... -55°C to +150°C



### Characteristics $T_A=25^\circ$ C

	Symbol	Min.	Typ.	Max.	Unit	Condition
<b>Emitter</b>						
Forward Voltage	$V_F$	—	1.2	1.5	V	$I_F=20$ mA
Reverse Voltage	$V_R$	5.0	—	—	V	$I_R=10$ $\mu$ A
Reverse Current	$I_R$	—	—	10	$\mu$ A	$V_R=5.0$ V
<b>Detector</b>						
Forward Blocking Voltage	$V_{DRM}$	400	—	—	V	$R_{GK}=10$ K $\Omega$ $T_A=100^\circ$ C $I_d=150$ $\mu$ A
Reverse Blocking Voltage	$V_{DRRM}$	400	—	—	V	$R_{GK}=10$ K $\Omega$ $T_A=100^\circ$ C $I_d=150$ $\mu$ A
On-state Voltage	$V_t$	—	—	1.2	V	$I_T=100$ mA
Holding Current	$I_H$	—	—	500	$\mu$ A	$R_{GK}=27$ K $\Omega$ $V_{FX}=50$ V
Gate Trigger Voltage	$V_{GT}$	—	0.6	1.0	V	$V_{FX}=100$ V $R_{GK}=27$ K $\Omega$ $R_L=10$ K $\Omega$
Forward Leakage Current	$I_D$	—	0.2	2.0	$\mu$ A	$R_{GK}=27$ K $\Omega$ $V_{RX}=400$ V $I_F=0$ , $T_A=25^\circ$ C
Reverse Leakage Current	$I_R$	—	0.2	2.0	$\mu$ A	$R_{GK}=27$ K $\Omega$ $V_{RX}=400$ V $I_F=0$ , $T_A=25^\circ$ C
Gate Trigger Current	$I_{GT}$	—	20	50	$\mu$ A	$V_{FX}=100$ V $R_{GK}=27$ K $\Omega$ , $R_L=10$ K $\Omega$
<b>Package</b>						
Turn-On Current	$I_{FT}$	0.5	5.0	10.0	mA	$V_{FX}=100$ V $R_{GK}=27$ K $\Omega$
Isolation Capacitance	—	—	—	2	pF	f=1.0 MHz